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3.3V CMOS Static RAM
4 Meg (256K x 16-Bit)

IDT71V416S
IDT71V416L

Features

- **256K x 16 advanced high-speed CMOS Static RAM**
- **JEDEC Center Power / GND pinout for reduced noise.**
- **Equal access and cycle times**
  - *Commercial and Industrial: 10/12/15ns*
- **One Chip Select plus one Output Enable pin**
- **Bidirectional data inputs and outputs directly LVTTL-compatible**
- **Low power consumption via chip deselect**
- **Upper and Lower Byte Enable Pins**
- **Single 3.3V power supply**
- **Available in 44-pin, 400 mil plastic SOJ package and a 44-pin, 400 mil TSOP Type II package and a 48 ball grid array, 9mm x 9mm package.**
- **Green parts available, see ordering information**

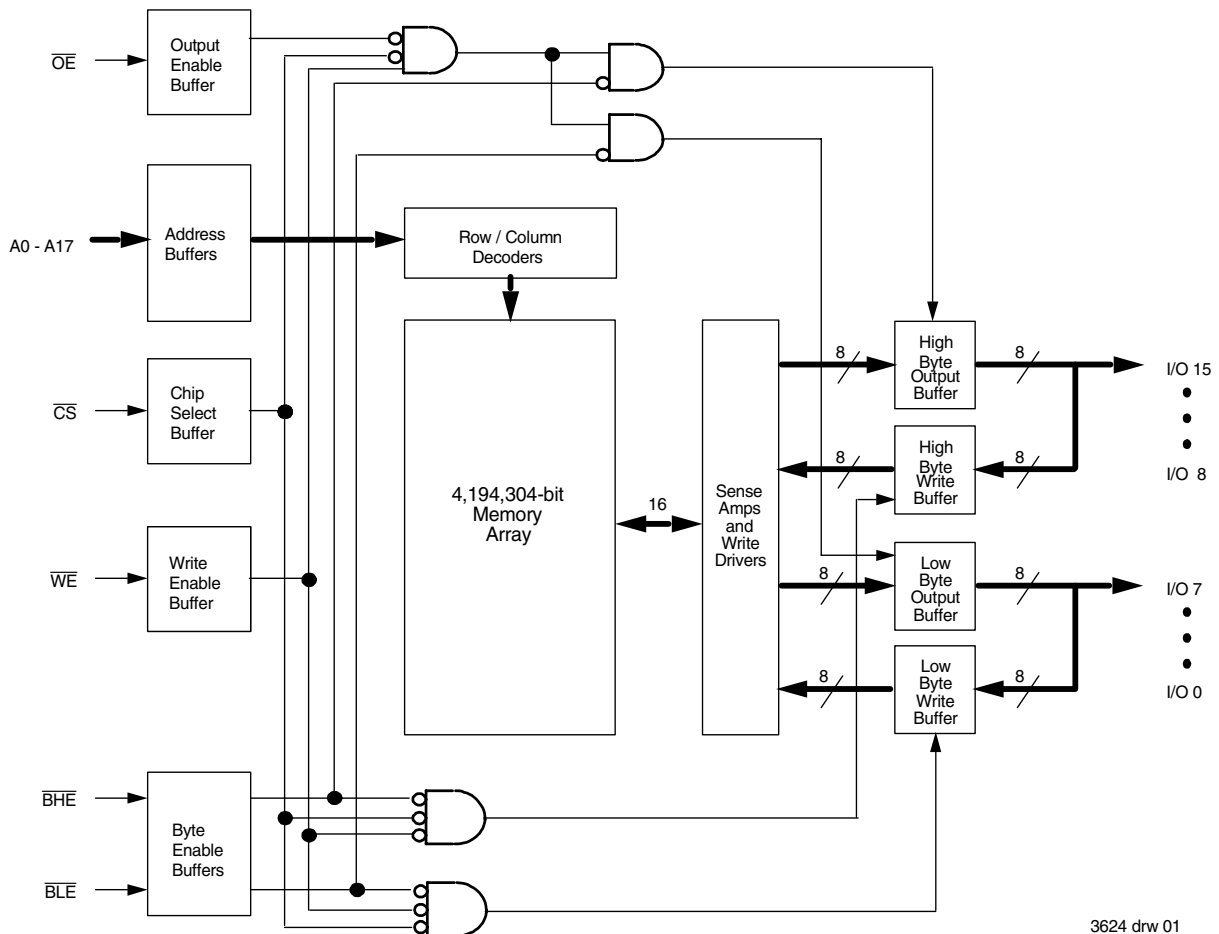## Description

The IDT71V416 is a 4,194,304-bit high-speed Static RAM organized as 256K x 16. It is fabricated using high-performance, high-reliability CMOS technology. This state-of-the-art technology, combined with innovative circuit design techniques, provides a cost-effective solution for high-speed memory needs.

The IDT71V416 has an output enable pin which operates as fast as 5ns, with address access times as fast as 10ns. All bidirectional inputs and outputs of the IDT71V416 are LVTTL-compatible and operation is from a single 3.3V supply. Fully static asynchronous circuitry is used, requiring no clocks or refresh for operation.

The IDT71V416 is packaged in a 44-pin, 400 mil Plastic SOJ and a 44-pin, 400 mil TSOP Type II package and a 48 ball grid array, 9mm x 9mm package.
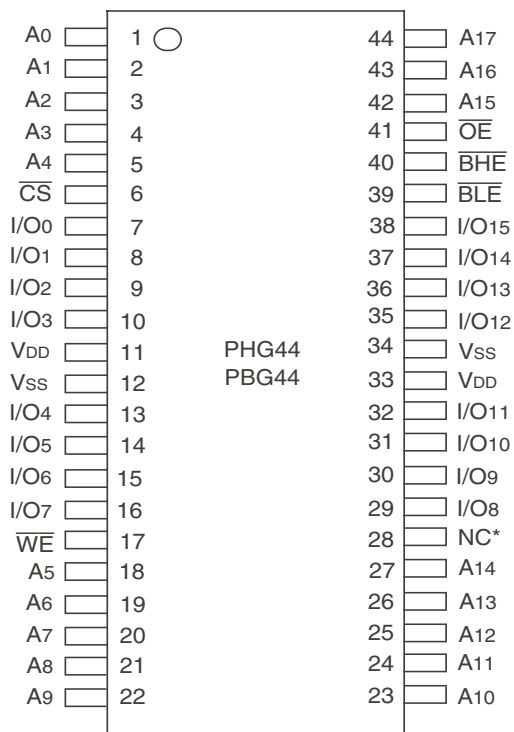
Functional Block Diagram

3624 drw 01

DSC-3624/11

Pin Configurations - SOJ/TSOP

3624 drw 02

*Pin 28 can either be a NC or connected to Vss

Top View

Pin Configurations - 48 BGA

71V416BE
BE48
48- BGA

3624 tbl 11

Top View

Pin Descriptions

A_0 - A_{17}	Address Inputs	Input
$\overline{CS}$	Chip Select	Input
$\overline{WE}$	Write Enable	Input
$\overline{OE}$	Output Enable	Input
$\overline{BHE}$	High Byte Enable	Input
$\overline{BLE}$	Low Byte Enable	Input
I/O_0 - I/O_{15}	Data Input/Output	I/O
V_{DD}	3.3V Power	Pwr
V_{SS}	Ground	Gnd

3624 tbl 01

SOJ Capacitance

(T_A = +25°C, f = 1.0MHz)

Symbol	Parameter[1]	Conditions	Max.	Unit
C_{IN}	Input Capacitance	V_{IN} = 3dV	7	pF
$C_{I/O}$	I/O Capacitance	V_{OUT} = 3dV	8	pF

3624 tbl 02

48 BGA Capacitance

(T_A = +25°C, f = 1.0MHz)

Symbol	Parameter[1]	Conditions	Max.	Unit
C_{IN}	Input Capacitance	V_{IN} = 3dV	6	pF
$C_{I/O}$	I/O Capacitance	V_{OUT} = 3dV	7	pF

3624 tbl 02b

NOTE:
1. This parameter is guaranteed by device characterization, but not production tested.

Absolute Maximum Ratings[1]

Symbol	Rating	Value	Unit
V_{DD}	Supply Voltage Relative to V_{SS}	-0.5 to +4.6	V
V_{IN}, V_{OUT}	Terminal Voltage Relative to V_{SS}	-0.5 to V_{DD}+0.5	V
T_{BIAS}	Temperature Under Bias	-55 to +125	°C
T_{STG}	Storage Temperature	-55 to +125	°C
P_T	Power Dissipation	1	W
I_{OUT}	DC Output Current	50	mA

3624 tbl 04

NOTE:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Temperature and Supply Voltage

Grade	Temperature	V_{SS}	V_{DD}
Commercial	0°C to +70°C	0V	See Below
Industrial	–40°C to +85°C	0V	See Below

3624 tbl 05

Recommended DC Operating Conditions

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{DD}	Supply Voltage	3.0	3.3	3.6	V
V_{SS}	Ground	0	0	0	V
V_{IH}	Input High Voltage	2.0	—	V_{DD}+0.3[1]	V
V_{IL}	Input Low Voltage	-0.3[2]	—	0.8	V

3624 tbl 06

NOTES:

1. VIH (max.) = VDD+2V for pulse width less than 5ns, once per cycle.
2. VIL (min.) = –2V for pulse width less than 5ns, once per cycle.

Truth Table[1]

$\overline{CS}$	$\overline{OE}$	$\overline{WE}$	$\overline{BLE}$	$\overline{BHE}$	I/O_0-I/O_7	I/O_8-I/O_{15}	Function
H	X	X	X	X	High-Z	High-Z	Deselected - Standby
L	L	H	L	H	DATA_OUT	High-Z	Low Byte Read
L	L	H	H	L	High-Z	DATA_OUT	High Byte Read
L	L	H	L	L	DATA_OUT	DATA_OUT	Word Read
L	X	L	L	L	DATA_IN	DATA_IN	Word Write
L	X	L	L	H	DATA_IN	High-Z	Low Byte Write
L	X	L	H	L	High-Z	DATA_IN	High Byte Write
L	H	H	X	X	High-Z	High-Z	Outputs Disabled
L	X	X	H	H	High-Z	High-Z	Outputs Disabled

3624 tbl 03

NOTE:

1. H = V_{IH}, L = V_{IL}, X = Don't care.

DC Electrical Characteristics

(V$_{DD}$ = Min. to Max., Commercial and Industrial Temperature Ranges)

Symbol	Parameter	Test Conditions	IDT71V416 Min.	IDT71V416 Max.	Unit
|I$_{LI}$|	Input Leakage Current	V$_{CC}$ = Max., V$_{IN}$ = V$_{SS}$ to V$_{DD}$	—	5	µA
|I$_{LO}$|	Output Leakage Current	V$_{DD}$ = Max., $\overline{CS}$ = V$_{IH}$, V$_{OUT}$ = V$_{SS}$ to V$_{DD}$	—	5	µA
V$_{OL}$	Output Low Voltage	I$_{OL}$ = 8mA, V$_{DD}$ = Min.	—	0.4	V
V$_{OH}$	Output High Voltage	I$_{OH}$ = -4mA, V$_{DD}$ = Min.	2.4	—	V

3624 tbl 07

DC Electrical Characteristics[1, 2, 3]

(V$_{DD}$ = Min. to Max., V$_{LC}$ = 0.2V, V$_{HC}$ = V$_{DD}$ – 0.2V)

| Symbol	Parameter		71V416S/L10 Com'l.	71V416S/L10 Ind.	71V416S/L12 Com'l.	71V416S/L12 Ind.	71V416S/L15 Com'l.	71V416S/L15 Ind.	Unit
I$_{CC}$	Dynamic Operating Current $\overline{CS} \leq$ V$_{LC}$, Outputs Open, V$_{DD}$ = Max., f = f$_{MAX}$[4]	S	200	200	180	180	170	170	mA
		L	180	180	170	170	160	160	
I$_{SB}$	Dynamic Standby Power Supply Current $\overline{CS} \geq$ V$_{HC}$, Outputs Open, V$_{DD}$ = Max., f = f$_{MAX}$[4]	S	70	70	60	60	50	50	mA
		L	50	50	45	45	40	40	
I$_{SB1}$	Full Standby Power Supply Current (static) $\overline{CS} \geq$ V$_{HC}$, Outputs Open, V$_{DD}$ = Max., f = 0[4]	S	20	20	20	20	20	20	mA
		L	10	10	10	10	10	10	

3624 tbl 08

NOTES:
1. All values are maximum guaranteed values.
2. All inputs switch between 0.2V (Low) and V$_{DD}$ -0.2V (High).
3. Power specifications are preliminary.
4. f$_{MAX}$ = 1/t$_{RC}$ (all address inputs are cycling at f$_{MAX}$); f = 0 means no address input lines are changing.
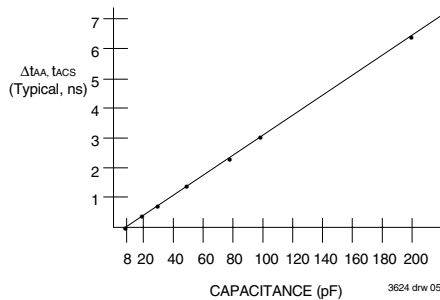
AC Test Loads
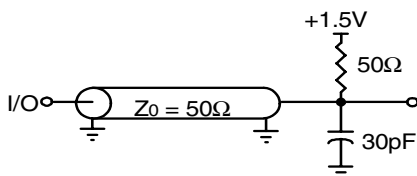
3624 drw 03

Figure 1. AC Test Load
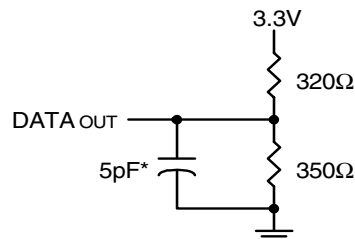
3624 drw 04

*Including jig and scope capacitance.

Figure 2. AC Test Load
(for t$_{CLZ}$, t$_{OLZ}$, t$_{CHZ}$, t$_{OHZ}$, t$_{OW}$, and t$_{WHZ}$)

3624 drw 05

Figure 3. Output Capacitive Derating

AC Test Conditions

Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	1.5ns
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
AC Test Load	Figures 1,2 and 3

3624 tbl 09

AC Electrical Characteristics

(V$_{DD}$ = Min. to Max., Commercial and Industrial Temperature Ranges)

Symbol	Parameter	71V416S/L10 Min.	71V416S/L10 Max.	71V416S/L12 Min.	71V416S/L12 Max.	71V416S/L15 Min.	71V416S/L15 Max.	Unit
READ CYCLE								
t$_{RC}$	Read Cycle Time	10	—	12	—	15	—	ns
t$_{AA}$	Address Access Time	—	10	—	12	—	15	ns
t$_{ACS}$	Chip Select Access Time	—	10	—	12	—	15	ns
t$_{CLZ}$[1]	Chip Select Low to Output in Low-Z	4	—	4	—	4	—	ns
t$_{CHZ}$[1]	Chip Select High to Output in High-Z	—	5	—	6	—	7	ns
t$_{OE}$	Output Enable Low to Output Valid	—	5	—	6	—	7	ns
t$_{OLZ}$[1]	Output Enable Low to Output in Low-Z	0	—	0	—	0	—	ns
t$_{OHZ}$[1]	Output Enable High to Output in High-Z	—	5	—	6	—	7	ns
t$_{OH}$	Output Hold from Address Change	4	—	4	—	4	—	ns
t$_{BE}$	Byte Enable Low to Output Valid	—	5	—	6	—	7	ns
t$_{BLZ}$[1]	Byte Enable Low to Output in Low-Z	0	—	0	—	0	—	ns
t$_{BHZ}$[1]	Byte Enable High to Output in High-Z	—	5	—	6	—	7	ns
WRITE CYCLE								
t$_{WC}$	Write Cycle Time	10	—	12	—	15	—	ns
t$_{AW}$	Address Valid to End of Write	8	—	8	—	10	—	ns
t$_{CW}$	Chip Select Low to End of Write	8	—	8	—	10	—	ns
t$_{BW}$	Byte Enable Low to End of Write	8	—	8	—	10	—	ns
t$_{AS}$	Address Set-up Time	0	—	0	—	0	—	ns
t$_{WR}$	Address Hold from End of Write	0	—	0	—	0	—	ns
t$_{WP}$	Write Pulse Width	8	—	8	—	10	—	ns
t$_{DW}$	Data Valid to End of Write	5	—	6	—	7	—	ns
t$_{DH}$	Data Hold Time	0	—	0	—	0	—	ns
t$_{OW}$[1]	Write Enable High to Output in Low-Z	3	—	3	—	3	—	ns
t$_{WHZ}$[1]	Write Enable Low to Output in High-Z	—	6	—	7	—	7	ns

3624 tbl 10

NOTE:
1. This parameter is guaranteed with the AC Load (Figure 2) by device characterization, but is not production tested.

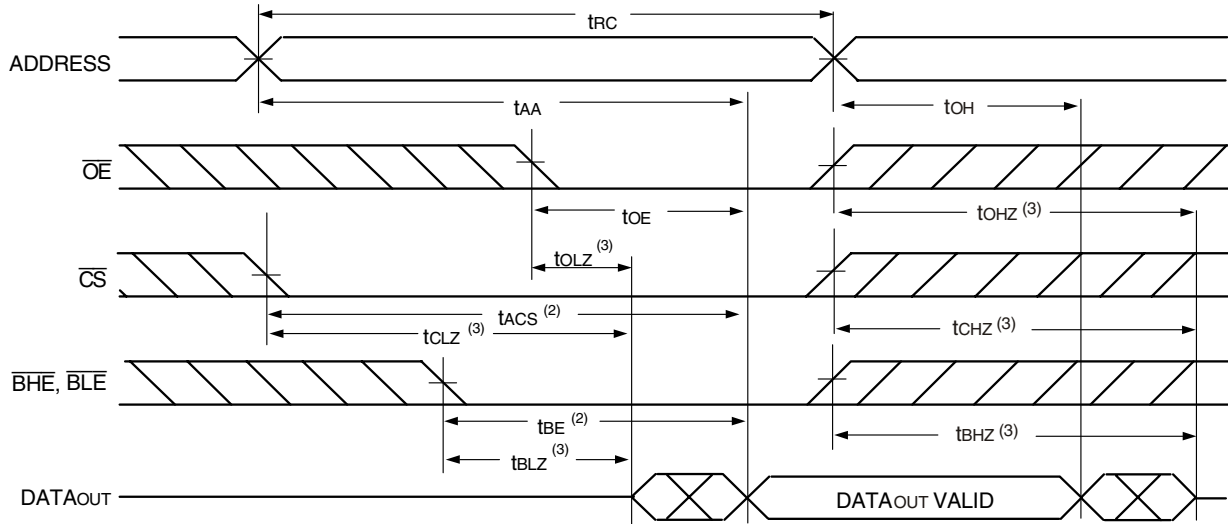## Timing Waveform of Read Cycle No. 1[1,2,3]
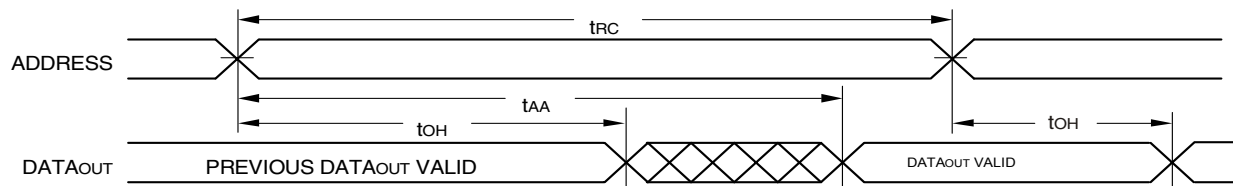
3624 drw 06

NOTES:
1. $\overline{WE}$ is HIGH for Read Cycle.
2. Device is continuously selected, $\overline{CS}$ is LOW.
3. $\overline{OE}$, $\overline{BHE}$, and $\overline{BLE}$ are LOW.
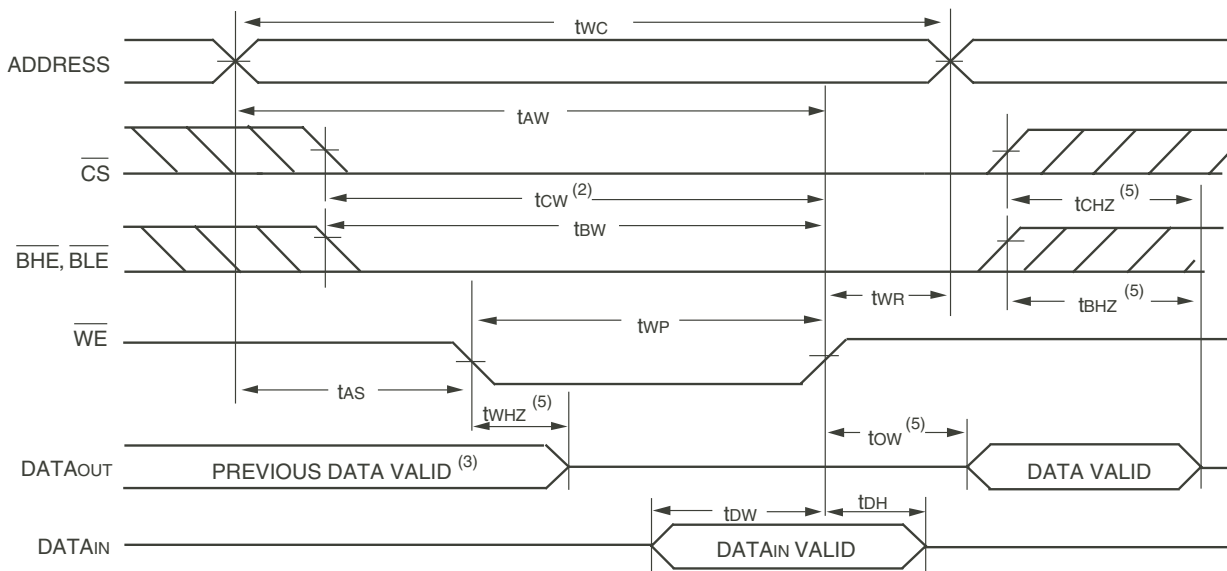
Timing Waveform of Read Cycle No. 2[1]

3624 drw 07

NOTES:
1. $\overline{WE}$ is HIGH for Read Cycle.
2. Address must be valid prior to or coincident with the later of $\overline{CS}$, $\overline{BHE}$, or $\overline{BLE}$ transition LOW; otherwise t_{AA} is the limiting parameter.
3. Transition is measured ±200mV from steady state.

Timing Waveform of Write Cycle No. 1 ($\overline{WE}$ Controlled Timing)[1,2,4]

3624 drw 08

NOTES:
1. A write occurs during the overlap of a LOW $\overline{CS}$, LOW $\overline{BHE}$ or $\overline{BLE}$, and a LOW $\overline{WE}$.
2. $\overline{OE}$ is continuously HIGH. If during a $\overline{WE}$ controlled write cycle $\overline{OE}$ is LOW, t_{WP} must be greater than or equal to $t_{WHZ} + t_{DW}$ to allow the I/O drivers to turn off and data to be placed on the bus for the required t_{DW}. If $\overline{OE}$ is HIGH during a $\overline{WE}$ controlled write cycle, this requirement does not apply and the minimum write pulse is as short as the specified t_{WP}.
3. During this period, I/O pins are in the output state, and input signals must not be applied.
4. If the $\overline{CS}$ LOW or $\overline{BHE}$ and $\overline{BLE}$ LOW transition occurs simultaneously with or after the $\overline{WE}$ LOW transition, the outputs remain in a high-impedance state.
5. Transition is measured ±200mV from steady state.

Timing Waveform of Write Cycle No. 2 ($\overline{CS}$ Controlled Timing)[1,3]

3624 drw 09

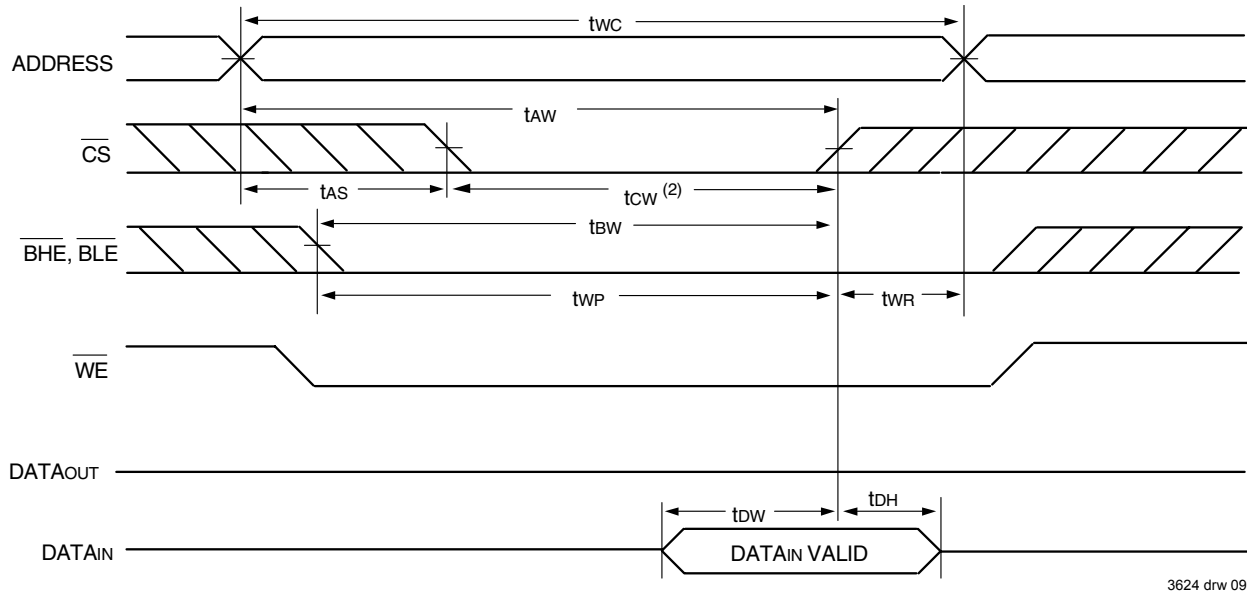## Timing Waveform of Write Cycle No. 3 ($\overline{BHE}$, $\overline{BLE}$ Controlled Timing)[1,3]

3624 drw 10

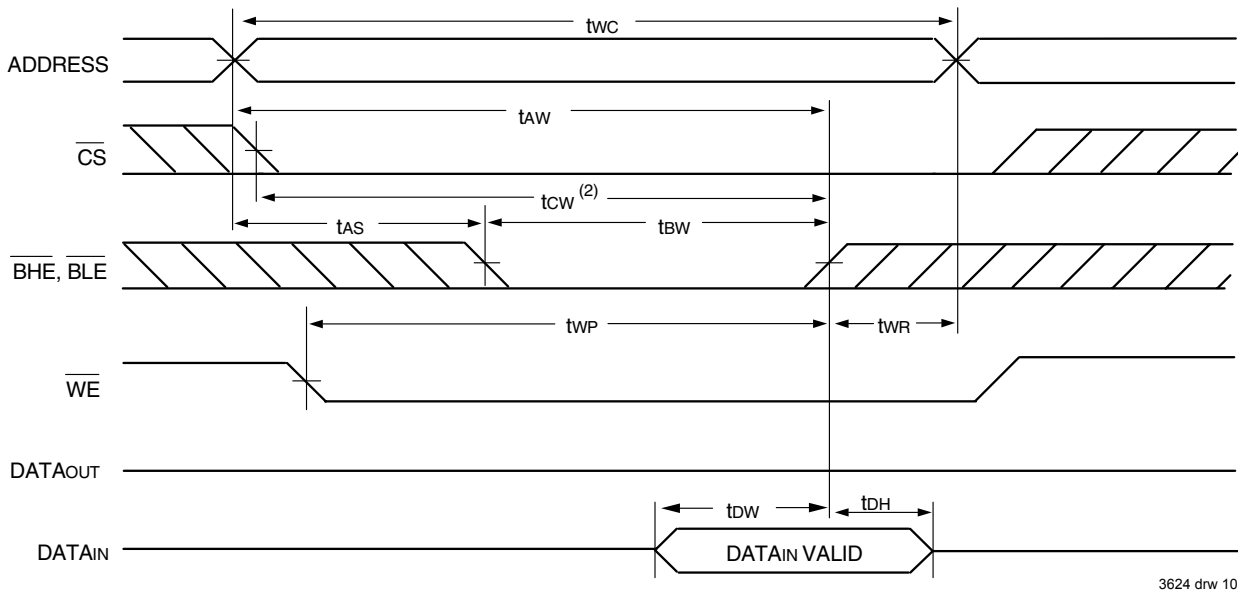**NOTES:**
1. A write occurs during the overlap of a LOW $\overline{CS}$, LOW $\overline{BHE}$ or $\overline{BLE}$, and a LOW $\overline{WE}$.
2. During this period, I/O pins are in the output state, and input signals must not be applied.
3. If the $\overline{CS}$ LOW or $\overline{BHE}$ and $\overline{BLE}$ LOW transition occurs simultaneously with or after the $\overline{WE}$ LOW transition, the outputs remain in a high-impedance state.

Ordering Information
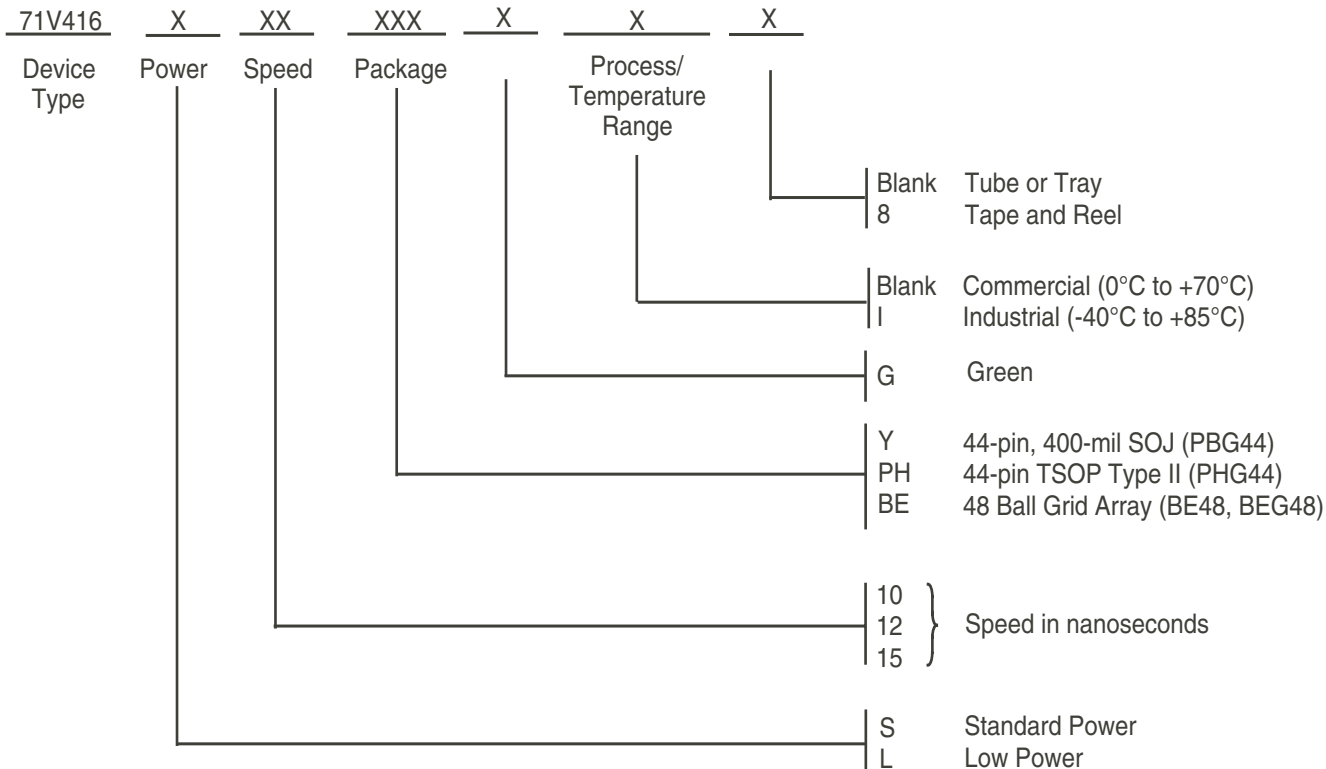
```
71V416    X     XX    XXX       X        X          X
```

Device Type   Power   Speed   Package

Process/
Temperature
Range

Blank	Tube or Tray
8	Tape and Reel

Blank	Commercial (0°C to +70°C)
I	Industrial (-40°C to +85°C)

G	Green

Y	44-pin, 400-mil SOJ (PBG44)
PH	44-pin TSOP Type II (PHG44)
BE	48 Ball Grid Array (BE48, BEG48)

10	
12	Speed in nanoseconds
15	

S	Standard Power
L	Low Power

3624 drw 11a

Orderable Part Information

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
10	71V416L10BE	BE48	CABGA	C
	71V416L10BEG	BEG48	CABGA	C
	71V416L10BEG8	BEG48	CABGA	C
	71V416L10PHG	PHG44	TSOP	C
	71V416L10PHG8	PHG44	TSOP	C
	71V416L10PHGI	PHG44	TSOP	I
	71V416L10PHGI8	PHG44	TSOP	I
	71V416L10YG	PBG44	SOJ	C
	71V416L10YG8	PBG44	SOJ	C
12	71V416L12BE	BE48	CABGA	C
	71V416L12BE8	BE48	CABGA	C
	71V416L12BEG	BEG48	CABGA	C
	71V416L12BEG8	BEG48	CABGA	C
	71V416L12BEGI	BEG48	CABGA	I
	71V416L12BEGI8	BEG48	CABGA	I
	71V416L12BEI	BE48	CABGA	I
	71V416L12BEI8	BE48	CABGA	I
	71V416L12PHG	PHG44	TSOP	C
	71V416L12PHG8	PHG44	TSOP	C
	71V416L12PHGI	PHG44	TSOP	I
	71V416L12PHGI8	PHG44	TSOP	I
	71V416L12YG	PBG44	SOJ	C
	71V416L12YG8	PBG44	SOJ	C
	71V416L12YGI	PBG44	SOJ	I
	71V416L12YGI8	PBG44	SOJ	I

3624 tbl 12a

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
10	71V416S10BE	BE48	CABGA	C
	71V416S10BE8	BE48	CABGA	C
	71V416S10BEG	BEG48	CABGA	C
	71V416S10BEG8	BEG48	CABGA	C
	71V416S10PHG	PHG44	TSOP	C
	71V416S10PHG8	PHG44	TSOP	C
	71V416S10PHGI	PHG44	TSOP	I
	71V416S10PHGI8	PHG44	TSOP	I
	71V416S10YG	PBG44	SOJ	C
	71V416S10YG8	PBG44	SOJ	C
12	71V416S12BE	BE48	CABGA	C
	71V416S12BE8	BE48	CABGA	C
	71V416S12BEG	BEG48	CABGA	C
	71V416S12BEG8	BEG48	CABGA	C
	71V416S12BEI	BE48	CABGA	I
	71V416S12BEI8	BE48	CABGA	I
	71V416S12PHG	PHG44	TSOP	C
	71V416S12PHG8	PHG44	TSOP	C
	71V416S12PHGI	PHG44	TSOP	I
	71V416S12PHGI8	PHG44	TSOP	I
	71V416S12YG	PBG44	SOJ	C
	71V416S12YG8	PBG44	SOJ	C
	71V416S12YGI	PBG44	SOJ	I
	71V416S12YGI8	PBG44	SOJ	I

3624 tbl 12b

Orderable Part Information (con't)

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
15	71V416L15BE	BE48	CABGA	C
	71V416L15BE8	BE48	CABGA	C
	71V416L15BEG	BEG48	CABGA	C
	71V416L15BEG8	BEG48	CABGA	C
	71V416L15BEGI	BEG48	CABGA	I
	71V416L15BEGI8	BEG48	CABGA	I
	71V416L15BEI	BE48	CABGA	I
	71V416L15BEI8	BE48	CABGA	I
	71V416L15PHG	PHG44	TSOP	C
	71V416L15PHG8	PHG44	TSOP	C
	71V416L15PHGI	PHG44	TSOP	I
	71V416L15PHGI8	PHG44	TSOP	I
	71V416L15YGI	PBG44	SOJ	I
	71V416L15YGI8	PBG44	SOJ	I

3624 tbl 12c

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
15	71V416S15BE	BE48	CABGA	C
	71V416S15BE8	BE48	CABGA	C
	71V416S15BEG	BEG48	CABGA	C
	71V416S15BEG8	BEG48	CABGA	C
	71V416S15BEGI	BEG48	CABGA	I
	71V416S15BEGI8	BEG48	CABGA	I
	71V416S15BEI	BE48	CABGA	I
	71V416S15BEI8	BE48	CABGA	I
	71V416S15PHG	PHG44	TSOP	C
	71V416S15PHG8	PHG44	TSOP	C
	71V416S15PHGI	PHG44	TSOP	I
	71V416S15PHGI8	PHG44	TSOP	I
	71V416S15YG	PBG44	SOJ	C
	71V416S15YG8	PBG44	SOJ	C
	71V416S15YGI	PBG44	SOJ	I
	71V416S15YGI8	PBG44	SOJ	I

3624 tbl 12d

Datasheet Document History

08/5/99		Updated to new format
	Pg 6	Revised footnote for t_{CW} on Write Cycle No. 1 diagram
08/31/99	Pg. 1–9	Added Industrial temperature range offering
	Pg. 9	Added Datasheet Document History
03/24/00	Pg. 6	Changed note to Write cycle No. 1 according to footnotes
08/10/00		Add 48 ball grid array package offering
	Pg. 1	Correct TTL to LVTTL
09/11/ 02	Pg. 2	Updated TBD information for the 48 BGA Capacitance table
11/26/02	Pg. 8	Added "Die Revision" to ordering information
07/31/03	Pg. 8	Updated note, L10 speed grade commercial temperature only and updated die stepping from YF to Y.
10/13/03	Pg. 8	Updated ordering information. Refer to 71V416YS and 71V416YL datasheet for latest generation die step.
01/30/04	Pg. 8	Added "Restricted hazardous substance device" to ordering information
02/01/13:	Pg. 1	Removed IDT reference to fabrication
	Pg. 8	Removed die revision information from the Ordering Information
11/18/16:	Pg. 2	Updated the orderable part numbers for all pin configurations
		Added the corrected configuration title for the 48 BGA pin configuration
		Reformatted SOJ/TSOP pins & labels. No change in functionality. It remains the same
	Pg.4	Updated the Industrial values and the footnote references in the DC Electrical table
	Pg. 5	Updated the footnote references in the AC Electrical table
	Pg. 8	Updated the orderable part numbers in the Ordering Information
	Pg. 8-9	Added orderable part information tables